

## ABSTRACT OF THE DISCLOSURE

5 In order to reduce a gate-source leakage current in a standby state, the gate insulating film of one of transistors in each of inverters IV1-IV5 is made thick. In a standby state, an input signal IN has L level and accordingly one of the transistors in inverters IV1-IV5 each that is connected to a main power supply line or a main ground line is turned on. The turned-on transistors have the gate insulating film which is made thicker than that of normal transistors to reduce the gate leakage current thereby reduce current consumption in the standby state.